

R-C Thermal Model Parameters

DESCRIPTION

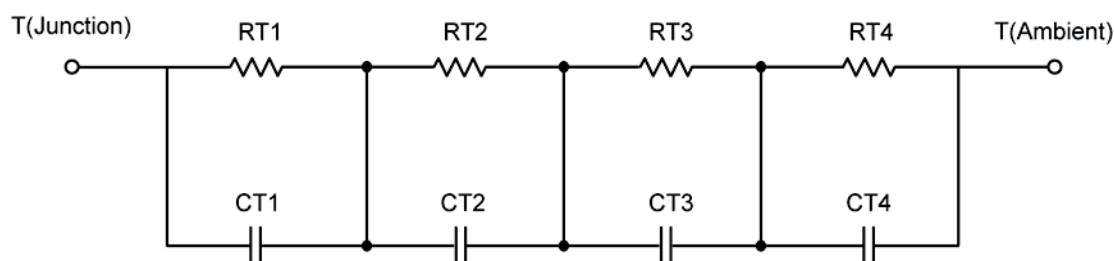
The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

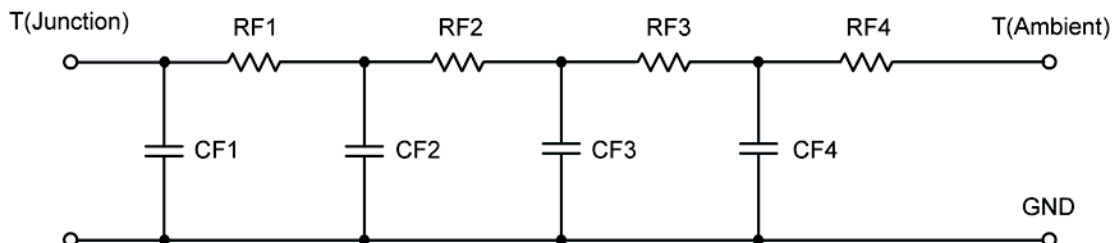
For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	281.9587	N/A	57.8141
RT2	29.0518	N/A	23.6881
RT3	72.9070	N/A	132.3185
RT4	65.3672	N/A	125.8739
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	3.8018 m	N/A	853.9395 u
CT2	229.6449 u	N/A	128.9626 u
CT3	333.2771 m	N/A	7.9274 m
CT4	1.2137 m	N/A	5.9823 m

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance ($^{\circ}\text{C}/\text{W}$)			
Junction to	Ambient	Case	Foot
RF1	18.8261	N/A	27.4996
RF2	111.3119	N/A	98.3288
RF3	255.0369	N/A	109.4772
RF4	64.7462	N/A	104.8220
Thermal Capacitance (Joules/ $^{\circ}\text{C}$)			
Junction to	Ambient	Case	Foot
CF1	27.2015 u	N/A	79.3220 u
CF2	659.2253 u	N/A	707.2300 u
CF3	3.4930 m	N/A	2.9952 m
CF4	382.5828 m	N/A	2.1667 m

Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya, IEEE / SEMITHERM 2002

